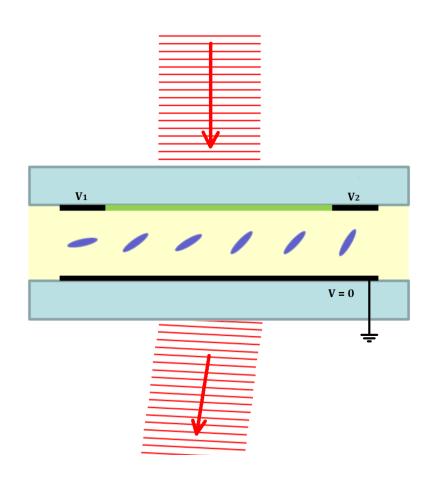
# Bundelsturing met een vloeibaar kristal

Enes Lievens – Nathan Sennesael – Roeland Van Haecke

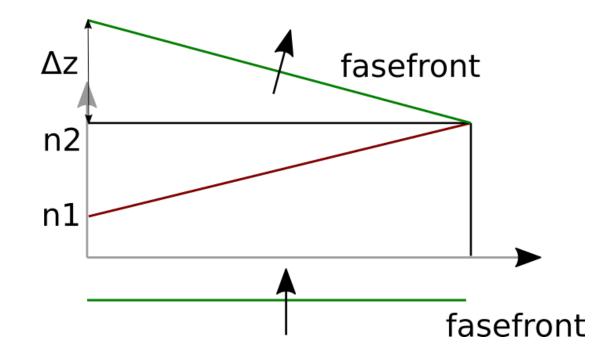
## Inleiding

- Doelstelling van dit project:
  - Inkomende vlakke lichtbundel deflecteren
  - Hoek exact elektronisch sturen
  - Hoek zo groot mogelijk
  - Device zo klein mogelijk



## Principe

- Typische waarden:
  - $\Delta n = 0.2$
  - $L = 50-100 \mu m$
  - d= 5-20 μm
- $\Theta \approx \Delta n d/L = 4.5^{\circ}$



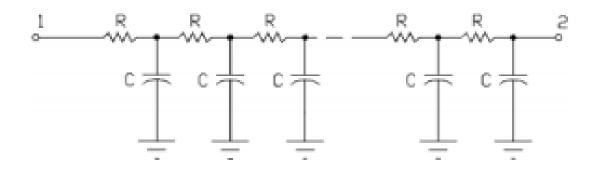
## Problemen met het 1e ontwerp

- 20µm vloeibaar kristal
- 5nm laag germanium

$$x_0^c = \sqrt{\frac{\sigma d d_1}{\omega \varepsilon_\perp}}$$

d = dikte LC $d_1 = dikte germanium$ 

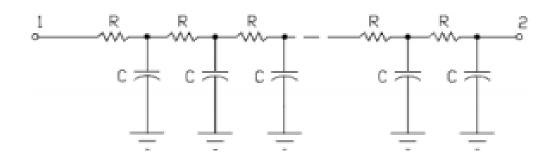


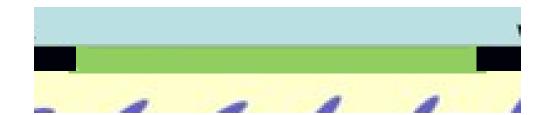


## De oplossing: dikker germanium

Dikte germanium: 5nm -> 50nm

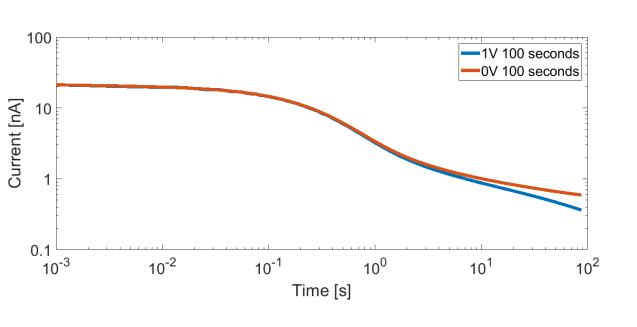
Karakteristieke lengte:  $x_c \rightarrow \sqrt{10} x_c$ 

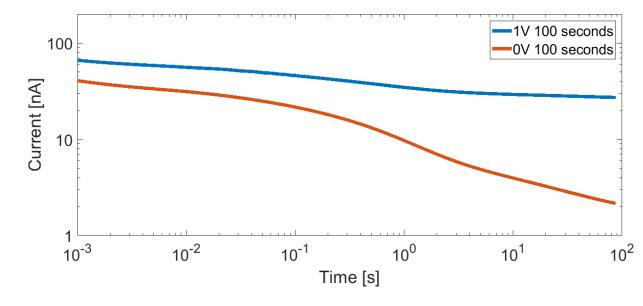




## IV metingen

#### Capactieve effecten treden op bij het te dun germanium

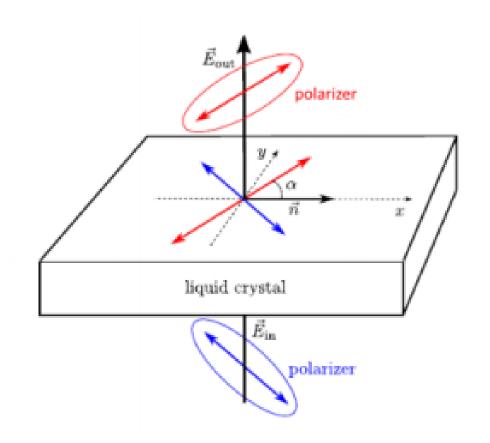




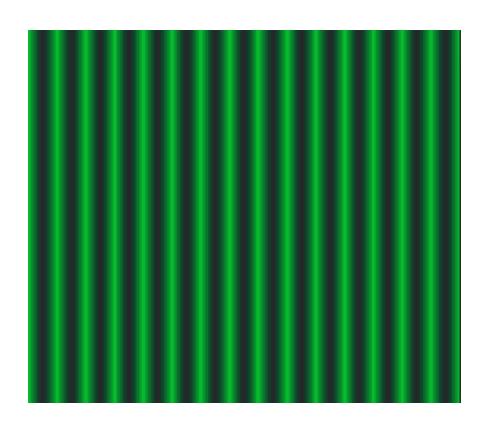
## Microscopie - Theorie

$$I = sin^2 \left( \frac{\pi \Delta nd}{\lambda} \right)$$

$$n_e(x) = n_o + Cx \Rightarrow I \propto sin^2 \left(\frac{C\pi d}{\lambda}x\right)$$



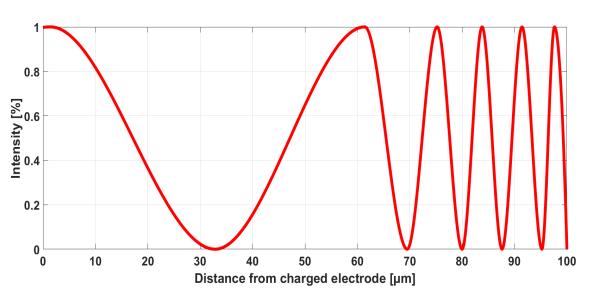
# Microscopie - Praktisch

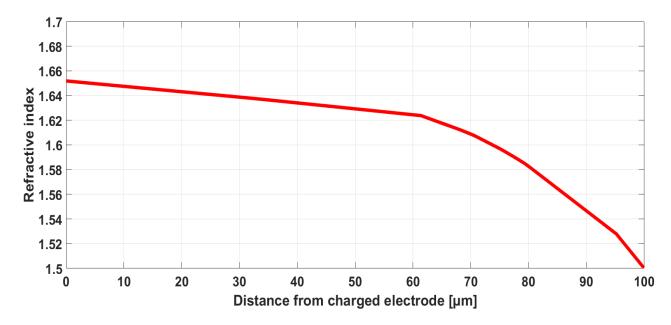




## Microscopie - Praktisch

$$n_e(x) = n_0 + \frac{\lambda}{\pi d} \arcsin(\sqrt{I(x)})$$
  
 $=> n_e(x) = n_0 + \frac{2\lambda}{Td}x$   
 $I(x) \propto \sin^2(\frac{2\pi}{T}x)$ 

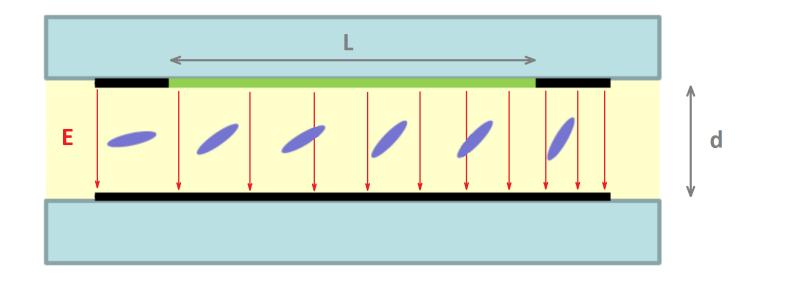


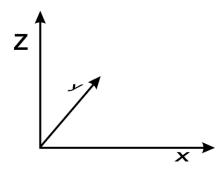


## 1D simulatie

$$d \ll L \implies \vec{E} \approx E \vec{u}_z$$

$$\frac{\mathrm{d}^2 V}{\mathrm{d}x^2} = j \frac{\omega \varepsilon_{eff}}{d_1 d\sigma} V$$





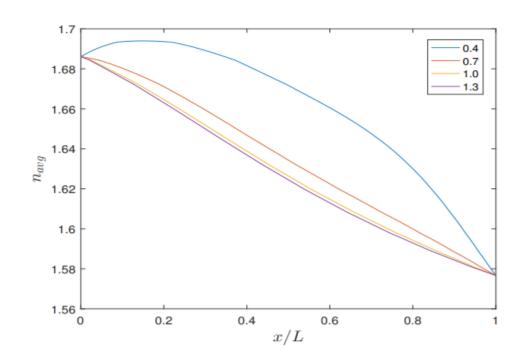
### 1D: conclusie

#### Meerdere frequenties:

$$\frac{\mathrm{d}^2 V_1}{\mathrm{d}x^2} = j \frac{\omega_1 \varepsilon_{eff}}{d_1 d\sigma} V_1$$
$$\frac{\mathrm{d}^2 V_2}{\mathrm{d}x^2} = j \frac{\omega_2 \varepsilon_{eff}}{d_1 d\sigma} V_2$$

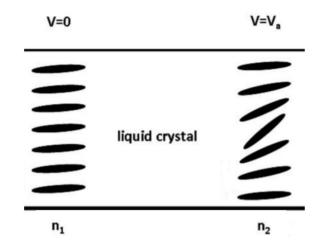
#### Eén frequentie:

$\theta(deg)$	$V_1(0)(V)$	$V_1(L)(V)$	$x_{c1}/L$	$V_2(0)(V)$	$V_2(L)(V)$	$x_{c2}/L$
0.5	1.06	1.32	1.00	0.00	0.00	0.97
1.0	1.06	1.57	1.00	0.00	0.01	1.04
1.5	1.03	1.88	1.00	0.00	0.03	1.07
2.0	1.00	2.22	1.00	0.00	0.02	1.47
2.2	0.98	2.21	1.00	0.00	0.03	1.44

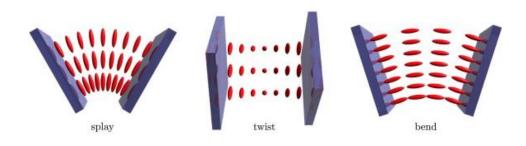


#### 2D simulatie

#### z - afhankelijkheid



#### Complex microscopisch gedrag



$$-\nabla\cdot(\overline{\overline{\varepsilon}}\,\nabla V)=0$$

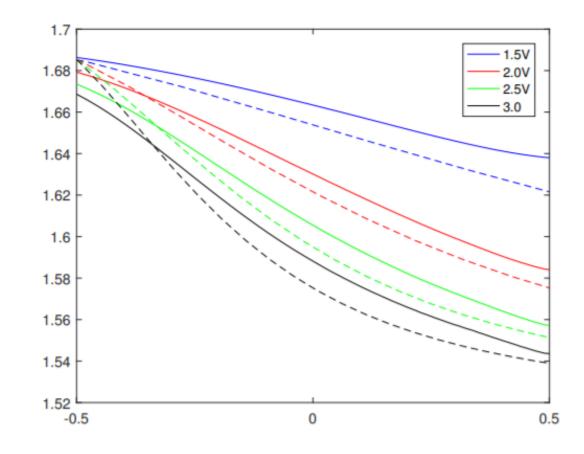
$$-K\nabla^2\theta = \frac{1}{2}\Delta\varepsilon \left(-\sin(2\theta)E_x^2 + \cos(2\theta)E_xE_z + \sin(2\theta)E_z^2\right)$$

### 2D: Conclusie

Rekenkundig veel intensiever

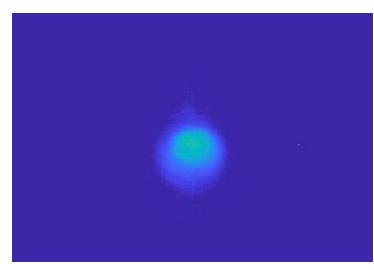
Trend gelijkaardig aan 1D simulatie

Algemeen: hogere brekingsindex

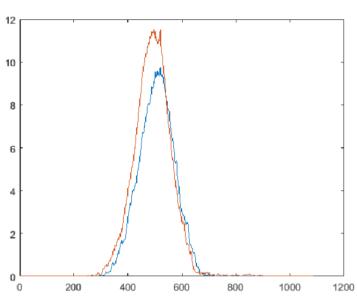


# Experimentatie

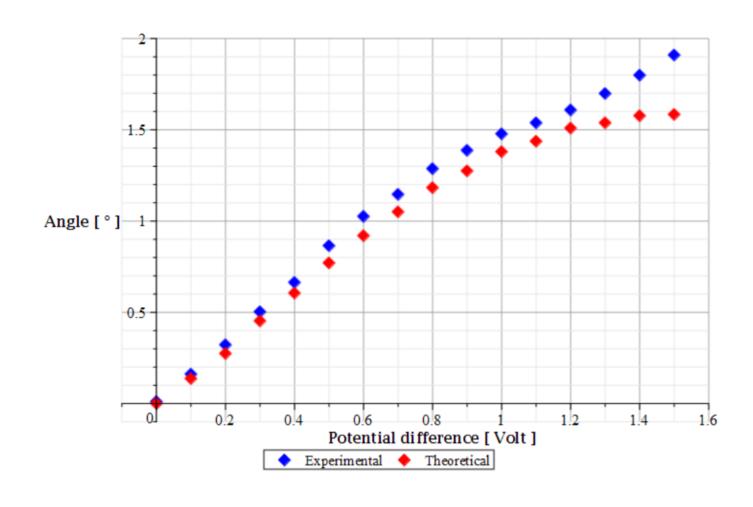






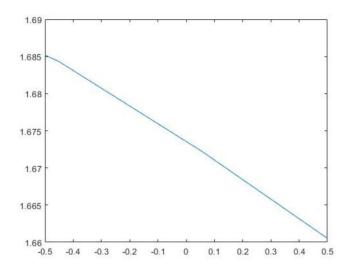


## Experimentele resultaten

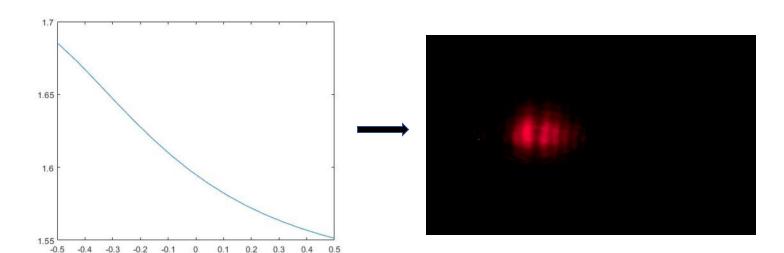


## Experimentele resultaten

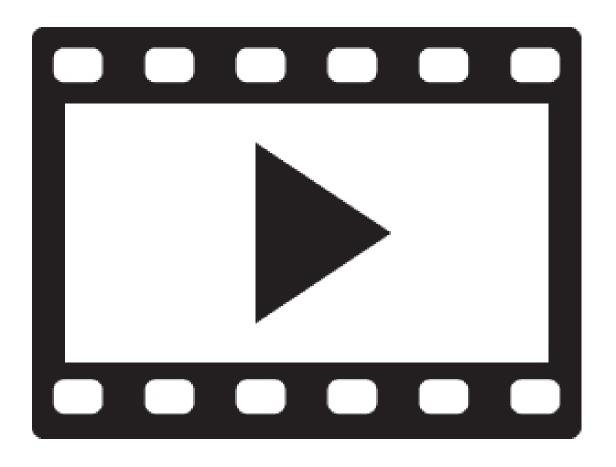
 $\Delta V = 0.2 \ Volt \ RMS$ 



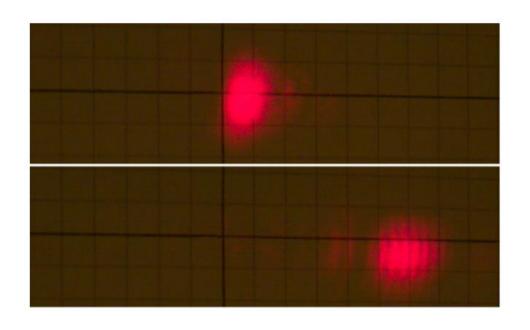
 $\Delta V = 1.5 \ Volt \ RMS$ 

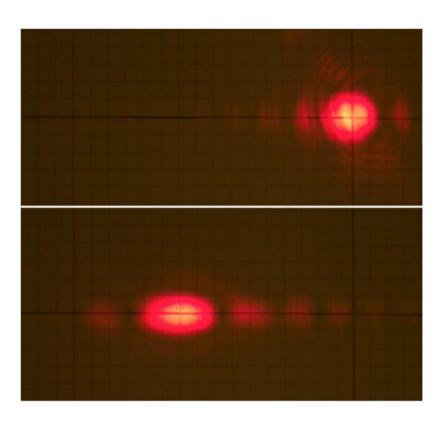


# Filmpjes

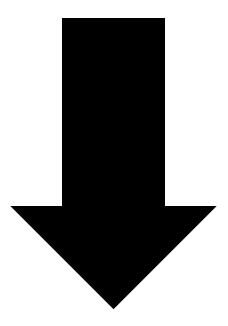


# Filmpjes

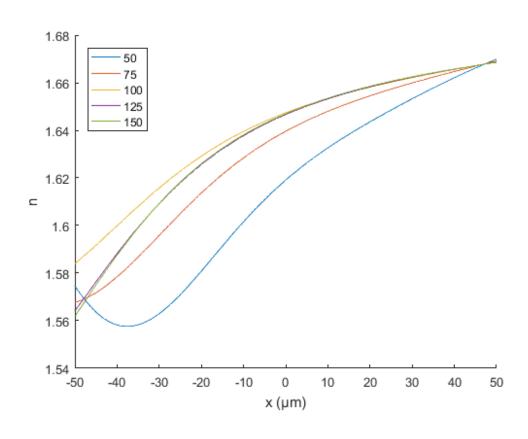




## Extra Slides



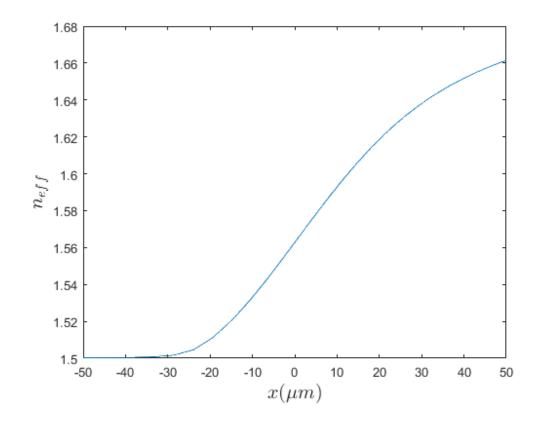
## (Gemiddelde) brekingsindex



- Duidelijk niet lineair
- Mogelijke oplossing:
  - Invoeren extra parameters en optimaliseren

## Optimalisatie

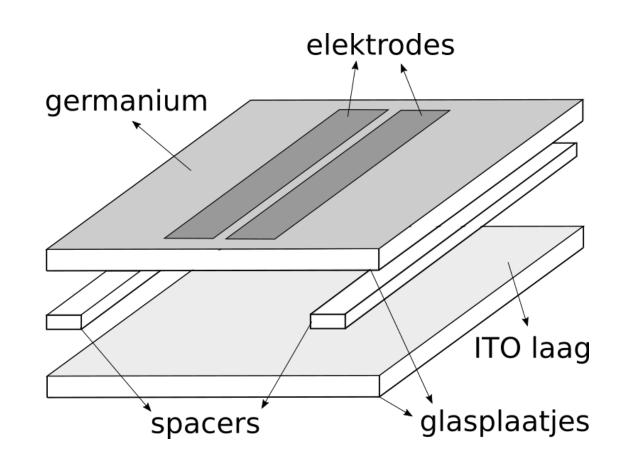
- Aanleggen meerdere frequenties
- Minimaliseren kostenfunctie: divergentie/stuurhoek
  - Moeilijk algoritmisch
  - Voorlopig trial and error
- Slechts beperkt gebied lineair



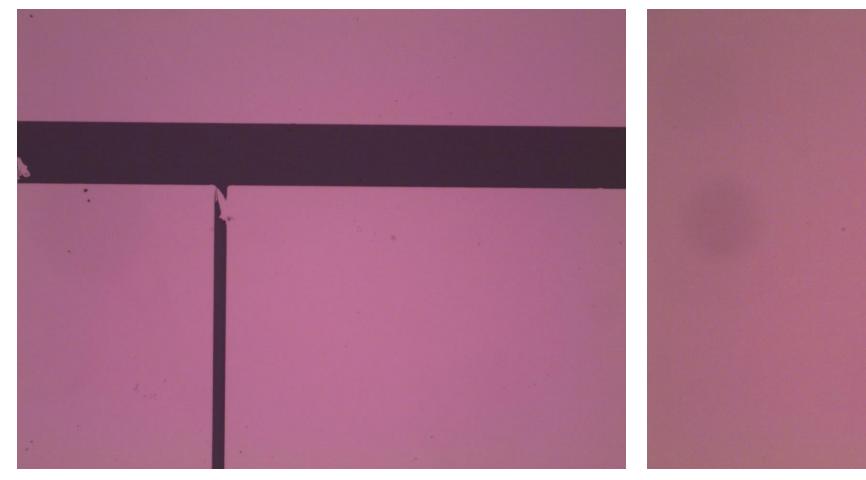


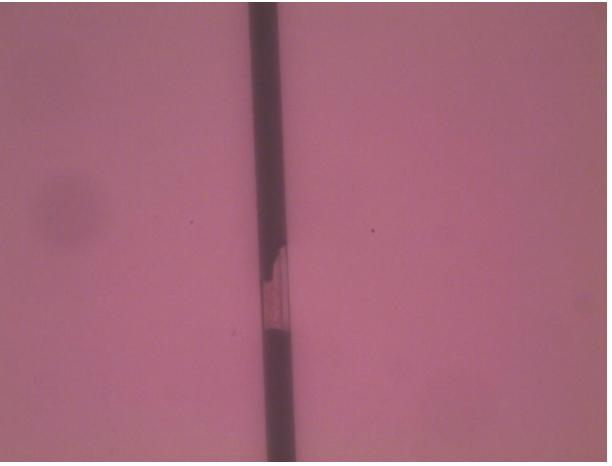
## Productie Sample

- 1. Glassubstraat met geleidende ITO-laag
- 2. Elektrodes: lithografie
- 3. Zwak geleidende laag: sputtering germanium
- 4. Uitlijningslaag: spincoating nylon
- 5. Vloeibaar kristal: capillaire werking



## MICROSCOOP

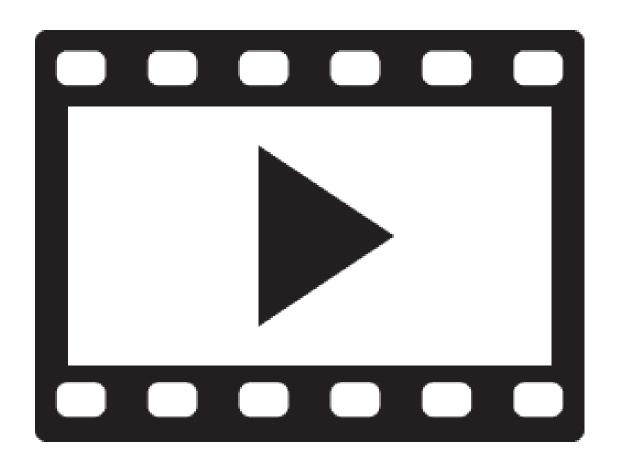




## Planning toekomst

- Moeilijkheden sample oplossen
  - Lijm, UV-lamp kapot?
  - Tussentijd: optimalisatie, 2D
- Experiment vergelijken met theorie
  - Revisie
  - Gegeven sturing realiseren

## Filmpje



## Extra slides (voor eventuele vragen toe te lichten)

